NSN 5961-01-129-9514

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-129-9514 **Inclosure Material:** Glass **Overall Length:** 0.725 inches **Terminal Length:** 0.220 inches **Overall Height:** 0.105 inches **Overall Width:** 0.280 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 40.0 collector to base voltage, dc all transistor and 40.0 collector to emitter voltage, dc all transistor and 5.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** 1.00 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 2.5 watts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: pnp **Precious Material And Location:** External surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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No